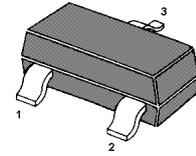
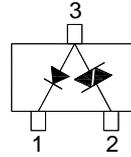


DB307CA

Silicon Rectifier and Trigger Composited Diodes



Marking Code: **D3R7**
TO-236 Plastic Package

Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Non-repetitive Peak Reverse Voltage for Rectifier	V_{RSM}	800	V
Repetitive Peak Reverse Voltage for Rectifier	V_{RRM}	800	V
Non-repetitive Peak Forward Surge Current (8.3 ms) for Rectifier	I_{FSM}	4	A
Repetitive Peak On-state Current ($t_p = 20\text{ }\mu\text{s}$, $f = 100\text{ Hz}$) for Trigger Diodes	I_{TRM}	2	A
Average Rectified Forward Current for Rectifier	$I_{F(AV)}$	200	mA
Operating Junction and Storage Temperature Range	T_j, T_{stg}	- 40 to + 125	$^\circ\text{C}$

Characteristics for Trigger Diodes at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit
Breakover Voltage at $C = 22\text{ nF}$	V_{BO}	28	36	V
Dynamic Breakover Voltage at $\Delta I = [I_{BO}\text{ to }I_F = 10\text{ mA}]$	ΔV	5	-	V
Breakover Current at $C = 22\text{ nF}$	I_{BO}	-	10	μA
Leakage Current at $V_B = 16\text{ V}$	I_B	-	1	μA

Characteristics for Rectifier at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit
Reverse Breakdown Voltage at $I_R = 100\text{ }\mu\text{A}$	$V_{(BR)R}$	800	-	V
Forward Voltage at $I_F = 200\text{ mA}$	V_F	-	1.2	V
Reverse Current at $V_R = 600\text{ V}$	I_R	-	5	μA

